A vertical surface mount semiconductor device, comprising: semiconductor device:

a plurality of bond pads disposed on a surface of said semiconductor device adjacent an edge thereof; and

conductive bumps disposed adjacent selected bond pads, each of said conductive bumps configured to form a conductive joint between one of said selected bond pads and a corresponding terminal of a substrate upon positioning said semiconductor device substantially vertically relative to said substrate.

- The vertical surface mount semiconductor device of claim 1, wherein a 2. conductive buth is disposed adjacent each of said plurality of bond pads.
- 3. The vertical surface mount semiconductor device of claim 1, further comprising a support layer.
- 4. The vertical surface mount semiconductor device of claim 3, wherein said support layer is disposed on another surface of said semiconductor device.
- 5. The vertical surface mount semiconductor device of claim 1, further comprising a support footing formed adjacent said edge.
- 6. The vertical surface mount semiconductor device of claim 5, wherein said support footing is disposed on another surface of said semiconductor device.
- 7. The vertical surface mount semiconductor device of claim 5, wherein said support footing is disposed on said surface of said semiconductor device.

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8. The vertical surface mount semiconductor device of claim 1, further comprising a laminate which connectively bonds said semiconductor device to an adjacent semiconductor device.

9. A vertical surface mount semiconductor device, comprising:

a plurality of bond pads disposed on a surface of said semiconductor device adjacent an edge thereof, selected bond pads of said plurality of bond pads having conductive bumps adjacent thereto, said conductive bumps configured to form a joints between said selected bond pads and corresponding terminals of a carrier substrate upon substantially perpendicular orientation of said semiconductor device on said carrier substrate; and

a support member, at least a portion of which is disposed proximate said edge of said semiconductor device.

- 10. The vertical surface mount semiconductor device of claim 9, wherein said support member is selected from the group consisting of support footings and support layers.
- 11. The vertical surface mount semiconductor device of claim 9, wherein said support member is disposed on another surface of said semiconductor device.
- 12. The vertical surface mount semiconductor device of claim 9, wherein a conductive bump is positioned adjacent each of said plurality of bond pads.

13. A chip-on-board assembly, comprising:

a substrate with a plurality of terminals;

a semiconductor device configured to be positioned substantially perpendicularly relative to said substrate, said semiconductor device having a plurality of bond pads on a

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surface thereof, each of said plurality of bond pads being located adjacent an edge of said surface; and electrically conductive joints configured to be disposed and to establish communication

between selected bond pads and corresponding terminals.

The chip-on-board assembly of claim 13, wherein each of said plurality of 14. bond pads has an electrically conductive joint disposed adjacent thereto.

The chip-on-board assembly of claim 13, further comprising a support member in contact with at least one of said semiconductor device and said carrier substrate

- The chip-on-board assembly of claim 15, wherein said support member is 16. selected from the group consisting of support footings and support layers.
- The chip-on-board assembly of claim 15, wherein said support member is 17. disposed proximate said edge of said semiconductor device.
- 18. The chip-on-board assembly of claim 13, wherein said semiconductor device is laminated to an adjacent semiconductor device.

A computer including a vertically mountable semiconductor device, the 19. semiconductor device comprising

a semiconductor die with a plurality of circuit traces;

a plurality of bond pads disposed on a surface of said semiconductor die proximate an edge thereof, each of/said plurality of bond pads communicating with one of said plurality of circuit traces; and

conductive bumps in communication with selected bond pads, said conductive bumps each configured/to form a joint between one of said selected bond pads and a

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corresponding terminal of a substrate when said semiconductor device is positioned substantially perpendicularly relative to said substrate.

- 20. The computer of claim 19, wherein each of said plurality of bond pads has a conductive bump in communication therewith.
- 21. The computer of claim 19, wherein said semiconductor device further comprises a support member.
- 22. The computer of claim 21, wherein said support member is selected from the group consisting of support footings and support layers.
- 23. The computer of claim 21, wherein said support member is disposed proximate said edge.
- 24. The computer of claim 19, wherein said semiconductor device is laminated to an adjacent semiconductor device.